NSN 5961-01-565-7191

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-565-7191 **Inclosure Material:** Glass and metal **Overall Length:** 0.333 inches **Overall Diameter:** 0.235 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-13 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 breakdown voltage, dc and 100.0 working peak reverse voltage **Current Rating Per Characteristic:** 50.00 amperes all primaries universal **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No